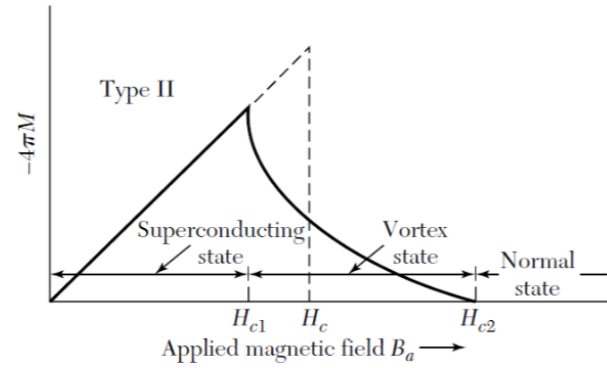
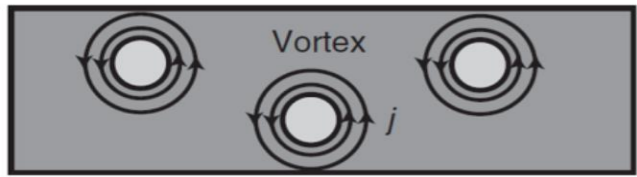


## Introduction

### Superconducting Vortex

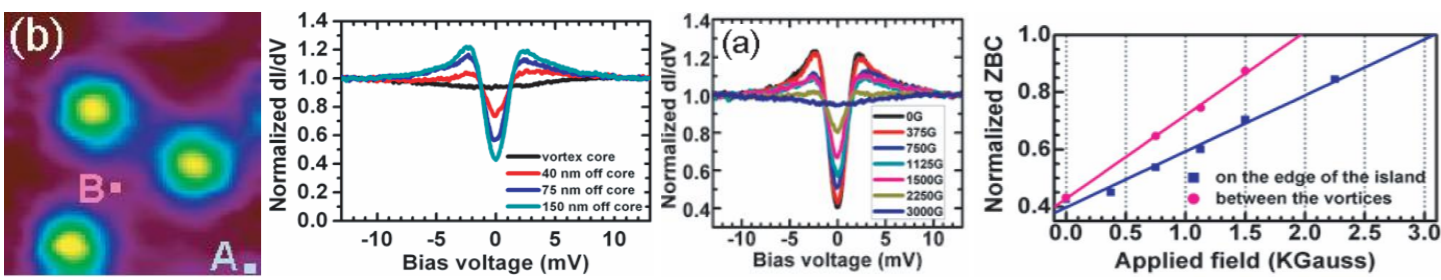


- Applied magnetic field between  $H_{c1}$  and  $H_{c2}$  magnetic flux enters sample in quantized form.

$$\Phi_0 = \frac{hc}{2e} \approx 2.07 \times 10^{-15} (T \cdot m^2)$$

- The superconducting vortices prevent the magnetic field from driving the rest of the sample into the non-superconducting state.

### Literature Review: 2D Pb island on Si(111)

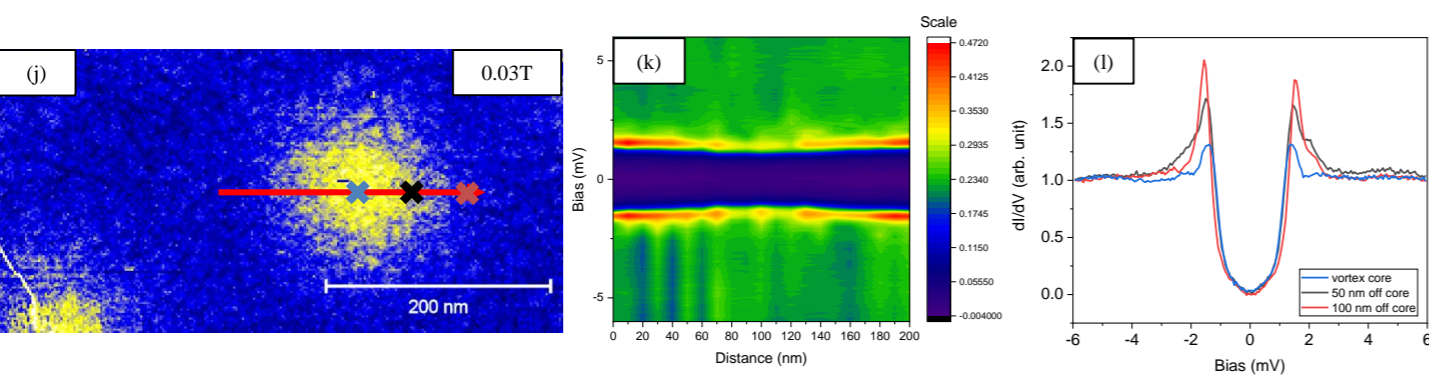
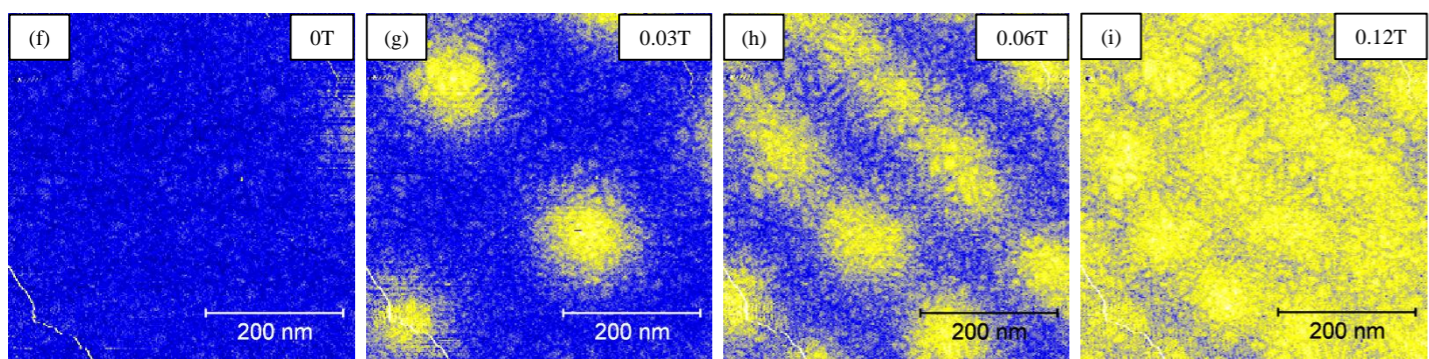
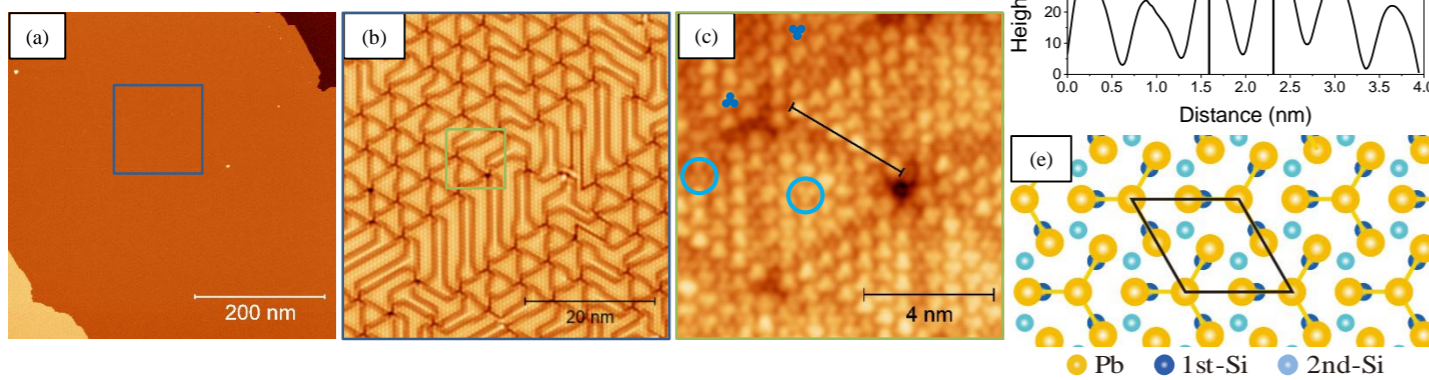


Ning, Y. X. et al. *Europhysics Letters (EPL)* **85**, 27004 (2009).

- When the magnetic field increases, the vortex density rises and superconducting gap correspondingly decreases.

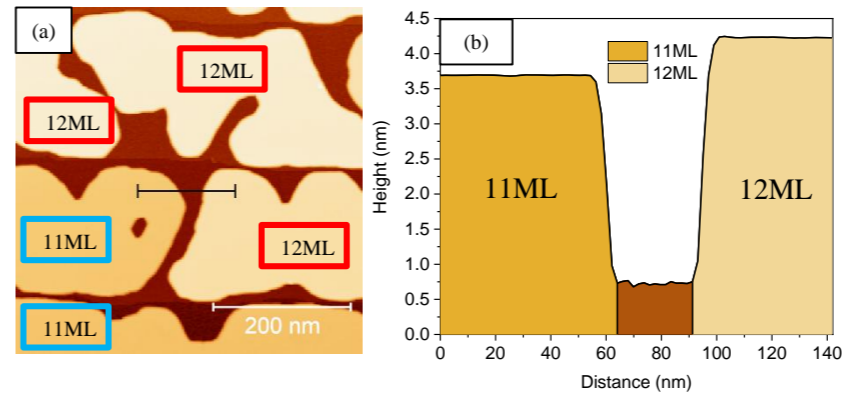
## Experimental Results

### Topography: Monolayer Pb/Si(111)

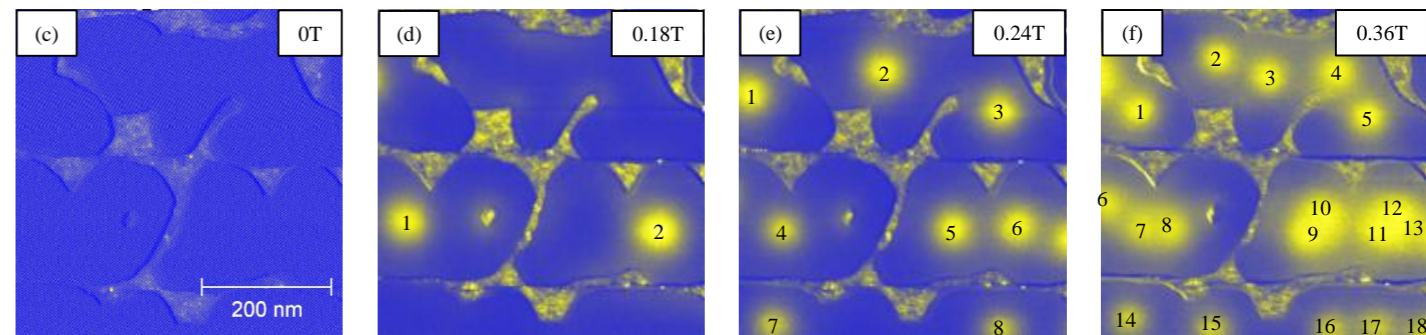


- Fig.(a)~(c), we zoom in Pb/Si(111)-SIC phase and observe the lattice constant is  $7.2 \pm 0.5 \text{ \AA}$ .
- As the magnetic field increases, the number of vortices increases, leading to a reduction in the vortex lattice constant  $d$ .
- Fig.(l), To remove the remaining superconducting gap at the vortex center, caused by a SC tip, a deconvolution process has been performed.
- The atomic-resolution image shows domains featuring upward- or downward-pointing triangles, within which four Pb atoms can be clearly identified forming the  $\sqrt{3} \times \sqrt{3}$  SIC structure.

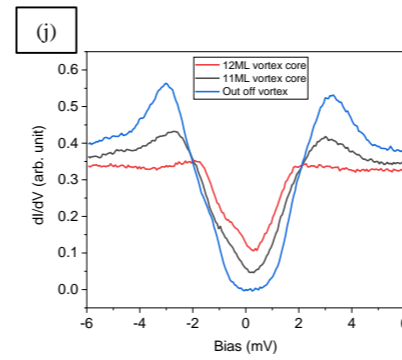
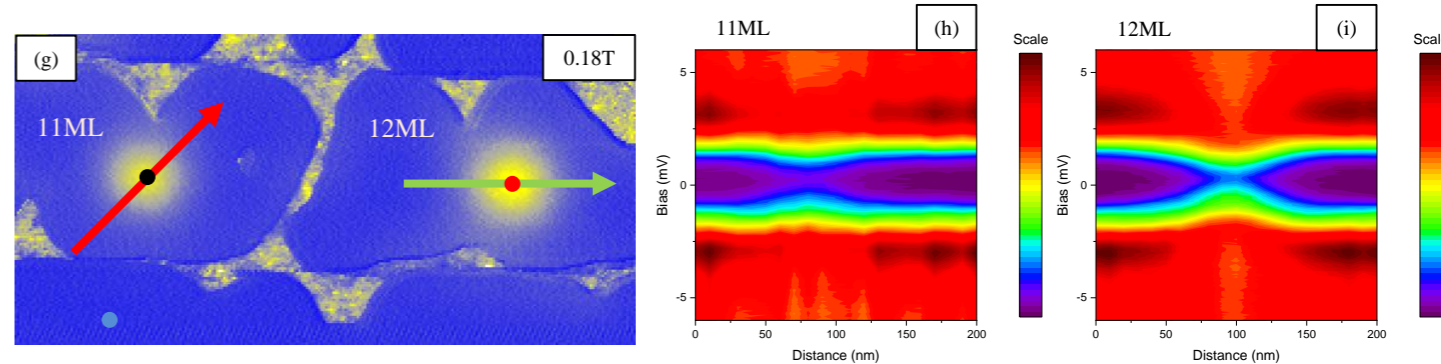
### Topography: Pb 2D Island on Si(111)



- Fig.(a), we observe different thickness islands. One with height 3.05nm, another is 3.51nm
- Here, 1 ML is defined as the interlayer spacing of Pb(111), which is 0.286 nm.



- The zero-bias conductance at the vortex core increases with the thickness of the Pb nano-islands due to the increased normal state conductance.



- The larger vortex size in the 12ML island indicates a longer coherence length ( $\xi_{GL}$ ) and a smaller critical field ( $H_{c2}$ ) compared with the 11-ML island.
- The superconducting gap at the vortex center is larger in 11 ML, whereas the zero-bias conductance is higher in 12 ML.

## Theoretical Calculations

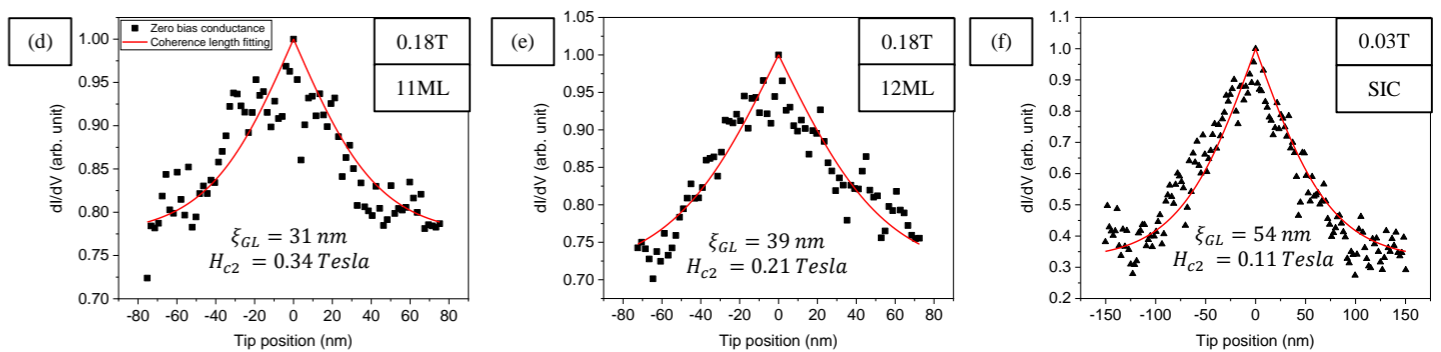
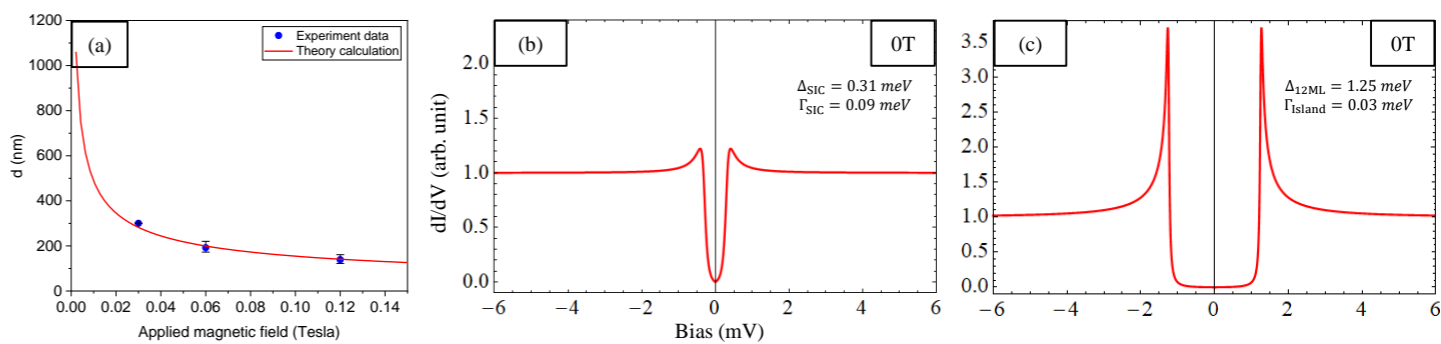
### Deconvolution method

- $\Delta_{SIC} = 0.31 \text{ meV}$ ;  $\Delta_{island} \approx \Delta_{Pb}$
- BCS fitting result
- To get  $\Delta_{Tip}$

$$\sigma(r, 0, T) = \sigma_0(T) + (1 - \sigma_0(T)) \times \left(1 - \tanh\left(\frac{|r|}{\sqrt{2} \cdot \xi_{GL}(T)}\right)\right)$$

$$H_{c2}(T) = \frac{\Phi_0}{2\pi \xi_{GL}^2(T)}, \Phi_0 \approx 2.07 \times 10^{-15} (T \cdot m^2)$$

$$d = \frac{\sqrt{2}\Phi_0}{\sqrt{3}H}$$



- Using the deconvolution method, we find that as the number of monolayers increases,  $\Delta$  increases and while the broadening parameter  $\Gamma$  decreases, likely because boundary effects become weaker in thicker films.
- From above plot, monolayer-SIC has the largest coherence length  $\xi_{GL}$  and smallest  $H_{c2}$ .
- The experimentally fitted value of the magnetic flux quantum is  $\Phi_0 = 2.34 \times 10^{-15} (T \cdot m^2)$ , which differs from the theoretical value by 1.73%.

## Summary

- We successfully fabricated Pb/Si(111) - SIC phase and also observed the SC vortices carrying a single magnetic flux quantum  $\Phi_0$ , with the vortex lattice structure following Abrikosov's theoretical prediction.
- We estimated the upper critical field ( $H_{c2}$ ) using Ginzburg-Landau theory, which is consistent with our results and those reported in previous studies.
- In 2D monolayer islands, the zero-bias conductance at the vortex core is higher in even-numbered layers than in odd-numbered layers.

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- Zhang, T., Cheng, P., Li, W.J. et al. Superconductivity in one-atomic-layer metal films grown on Si(111). *Nature Phys* **6**, 104–108 (2010).